TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC7WH04FU, TC7WH04FK

TRIPLE INVERTER

The TC7WH04 is an advanced high speed CMOS INVERTER fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

 High Speed $t_{pd} = 3.8$ ns (Typ.) at

Low Power Dissipation $I_{CC} = 2\mu A$ (Max.) at

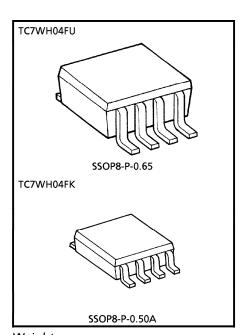
 $Ta = 25^{\circ}C$

High Noise Immunity $\cdots V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)

Power Down Protection is provided on all inputs.

Balanced Propagation Delays $\cdots t_{pLH} = t_{pHL}$

Wide Operating Voltage Range ··· \dot{V}_{CC} (opr) = 2~5.5V



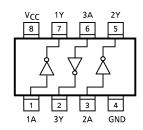
Weight

SSOP8-P-0.65 : 0.02g (Typ.) SSOP8-P-0.50A : 0.01g (Typ.)

MARKING

SM8 US8 Type Name H 0 4 Lot No. WН 04

PIN ASSIGNMENT (TOP VIEW)



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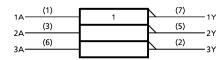
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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage Range	Vcc	-0.5~7.0	V	
DC Input Voltage	VIN	-0.5~7.0	٧	
DC Output Voltage	Vout	-0.5~V _{CC} + 0.5	V	
Input Diode Current	Ικ	- 20	mA	
Output Diode Current	^I ок	± 20	mA	
DC Output Current	lout	± 25	mA	
DC V _{CC} /Ground Current	lcc	± 50	mΑ	
Bower Dissination	D-	300 (SM8)	\A/	
Power Dissipation	PD	200 (US8)	mW	
Storage Temperature	T _{stg}	-65∼150	°C	
Lead Temperature (10 s)	TL	260	°C	

LOGIC DIAGRAM



TRUTH TABLE

Α	Υ
L	Н
Н	L

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	Vcc	2.0~5.5	V	
Input Voltage	VIN	0~5.5	V	
Output Voltage	VOUT	0~V _{CC}	V	
Operating Temperature	T _{opr}	- 40∼8 5	°C	
Input Rise and Fall Time	dt/dv	$0 \sim 100 \text{ (V}_{CC} = 3.3 \pm 0.3 \text{V)}$	ns /\/	
input kise and rail time	dt/dv	$0\sim20 \ (V_{CC} = 5 \pm 0.5V)$	ns/V	

DC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC SYMBOL TEST CONDITION		TEST CONDITION		Vcc	Ta = 25°C			Ta = -40~85°C		UNIT
		V _C C (V)	MIN.	TYP.	MAX.	MIN.	MAX.	OIVII		
High-Level				2.0	1.50	_	_	1.50	_	
Input Voltage	V _{IH}		_		V _{CC} × 0.7	-	_	V _C C × 0.7	_	V
Low-Level			_				0.50		0.50	
Input Voltage	V _{IL}					I	V _C C × 0.3	_	V _C C × 0.3	V
		V _{IN} = V _{IL}	I _{OH} = -50μA	2.0	1.9	2.0	_	1.9	_	V
High-Level	VOH			3.0	2.9	3.0	_	2.9	_	
Output Voltage				4.5	4.4	4.5	_	4.4	_	
Toutput Voltage			$I_{OH} = -4mA$	3.0	2.58		_	2.48	_	
			$I_{OH} = -8mA$	4.5	3.94		_	3.80	_	
		V _{IN} = V _{IH}	I _{OL} = 50μA	2.0	_	0.0	0.1		0.1	V
Low-Level				3.0	_	0.0	0.1	—	0.1	
Output Voltage	VOL			4.5	_	0.0	0.1		0.1	
Cutput Voltage			I _{OL} = 4mA	3.0	_	_	0.36	_	0.44	
			I _{OL} = 8mA	4.5	_	_	0.36	_	0.44	
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~ 5.5	-	1	± 0.1	_	± 1.0	μ A
Quiescent Supply Current	lcc	V _{IN} = V _{CC} or GND		5.5			2.0	_	20.0	μ A

AC ELECTRICAL	CHARACTERISTICS	(Input $t_r = t_f = 3ns$)
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CHARACTERISTIC SYMBOL		TEST (ONDITION	NOITION		Ta = 25°C			Ta = −40~85°C	
		•	V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	UNIT
Propagation Delay t _{pLH} Time t _{pHL}	1	3.3 ± 0.3	15		5.0	7.1	1.0	8.5		
		3.3 ± 0.3	50	_	7.5	10.6	1.0	12.0	ns	
		5.0 ± 0.5	15		3.8	5.5	1.0	6.5	115	
			50		5.3	7.5	1.0	8.5		
Input Capacitance	CIN		_			4	10	_	10	рF
Power Dissipation Capacitance	C _{PD}	(Note 1)			l	18	_	_		pF

(Note 1): CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

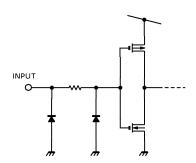
Average operating current can be obtained by the equation:

ICC (opr) = CpD · VCC · fIN + ICC

NOISE CHARACTERISTICS (Ta = 25°C, Input $t_r = t_f = 3$ ns)

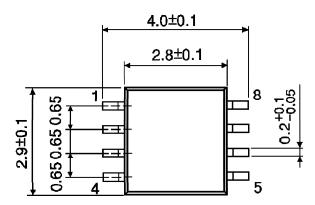
CHARACTERISTIC	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.3	-0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	_	3.5	٧
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	_	1.5	V

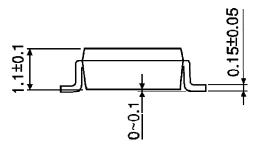
INPUT EQUIVALENT CIRCUIT



OUTLINE DRAWING SSOP8-P-0.65

Unit: mm

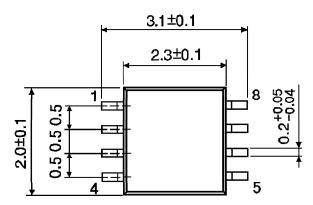


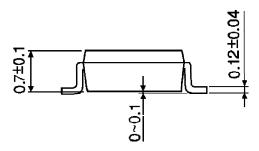


Weight: 0.02g (Typ.)

OUTLINE DRAWING SSOP8-P-0.50A

Unit: mm





Weight: 0.01g (Typ.)